

Power management (dual digital transistors)

IMD16A

Features

- 1) Two digital class transistors in a SMT package.
- 2) Up to 500mA can be driven.
- 3) Low $V_{CE(sat)}$ of drive transistors for low power dissipation.

•Package, marking, and packaging specifications

Part No.	IMD16A
Package	SMT6
Marking	D16
Code	T108
Basic ordering unit (pieces)	3000

•Absolute maximum ratings (Ta=25°C)

DII1 (PNP)				
Parameter	Symbol	Limits	Unit	
Supply voltage	Vcc	-50	V	
	Vin	-12	V	
Input voltage	VIIV	5	V	
Output current	lc	-500	mA	

DTr₂ (NPN)

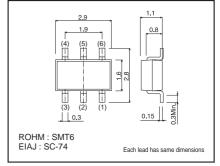
Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	50	V
Collector-emitter voltage	Vceo	50	V
Emitter-base voltage	Vebo	5	V
Collector current	lc	100	mA

Total

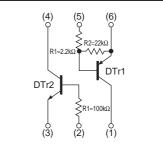
Parameter	Symbol	Limits	Unit
Collector power dissipation	Pd *	300(TOTAL)	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

* 200mW per element must not be exceeded.

•Dimensions (Unit : mm)



Inner circuit



•Electrical characteristics (Ta=25°C)

DTr₁

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Input voltage	VI(off)	_	-	-0.3	v	Vcc= -5V , Io= -100µA
	VI(on)	-2	_	_	v	Vo=-0.3V , Io=-20mA
Output voltage	VO(on)	_	_	-0.3	V	lo/l⊫ –50mA / –2.5mA
Input current	h	_	-	-3	mA	$V_{I}=-5V$
Output current	IO(off)	_	_	-0.5	μA	Vcc=-50V , Vi=0V
DC current gain	Gı *1	82	_	_	_	lo= -50mA , Vo= -5V
Transition frequency	f⊤ *2	-	250	-	MHz	Vc=-10V , I=50mA , f=100MHz
Input resistance	R1	1.54	2.2	2.86	kΩ	_
Resistance ratio	R2/R1	8	10	12	-	-

DTr₂

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	50	_	-	V	Ic=50μA
Collector-emitter breakdown voltage	BVCEO	50	-	-	V	Ic=1mA
Emitter-base breakdown voltage	ВVево	5	_	_	V	Ιε=50μΑ
Collector cutoff current	Ісво	-	-	0.5	μΑ	Vcb=50V
Emitter cutoff current	Іево	-	-	0.5	μA	VEB=4V
Collector-emitter saturation voltage	VCE(sat)	-	-	0.3	V	Ic/IB=1mA/0.1mA
DC current transfer ratio	hfe	100	250	600	-	Vce=5V , Ic=1mA
Transition frequency	f⊤ *	_	250	_	MHz	Vce=10V , Ie=-5mA , f=100MHz
Input resistance	R1	70	100	130	kΩ	_

*Transition frequency of mounted transistor.

500

20

100

DC CURRENT GAIN : GI

2.5

/I_B=10/

Ta=100°0

Ta=25°C

Та

5m 10m 20m 50m

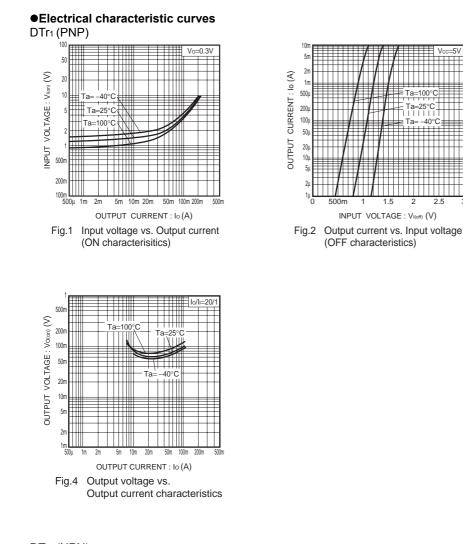
Fig.3 DC current gain vs.

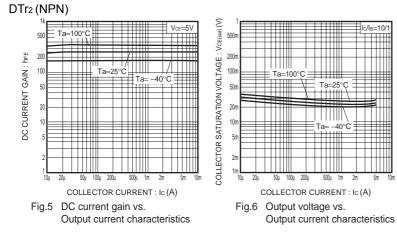
OUTPUT CURRENT : Io (A)

Output current characteristics

-40°C

Vo-5





	Notes
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